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Universal spin-polarization fluctuations in one-dimensional wires with magnetic impurities

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We study conductance and spin-polarization fluctuations in one-dimensional wires with spin-$5/2$ magnetic impurities (Mn). Our tight-binding Green function approach goes beyond the mean field thus including $s$-$d$ exchange-induced spin-flip scattering. In a certain parameter range, we find that spin-flip suppresses conductance fluctuations while enhancing spin-polarization fluctuations. More importantly, spin-polarization fluctuations attain a universal value $1/3$ for large enough spin-flip strengths. This intrinsic spin-polarization fluctuation may pose a severe limiting factor to the realization of steady spin-polarized currents in Mn-based one-dimensional wires.

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I. INTRODUCTION

Spin-related effects in solid state heterostructures give rise to a rich variety of fascinating physical phenomena. These spin-dependent properties also underlie a potential technological revolution in conventional electronics. This paradigm is termed “Spintronics.” A particularly interesting theme within this emerging field is spin-polarized transport in semiconductor heterostructures. This topic has attracted much attention after the fundamental discovery of exchange-induced spin-flip scattering. In a certain parameter range, we find that spin-flip suppresses conductance fluctuations while enhancing spin-polarization fluctuations. More importantly, spin-polarization fluctuations attain a universal value $1/3$ for large enough spin-flip strengths. This intrinsic spin-polarization fluctuation may pose a severe limiting factor to the realization of steady spin-polarized currents in Mn-based wires.

Here we discuss conductance and spin-polarization fluctuations in one-dimensional wires with spin-$5/2$ magnetic impurities (Mn). Our tight-binding Green function approach goes beyond the mean field thus including $s$-$d$ exchange-induced spin-flip scattering. In a certain parameter range, we find that spin-flip suppresses conductance fluctuations while enhancing spin-polarization fluctuations. More importantly, spin-polarization fluctuations attain a universal value $1/3$ for large enough spin-flip strengths. This intrinsic spin-polarization fluctuation may pose a severe limiting factor to the realization of steady spin-polarized currents in Mn-based wires.

II. HAMILTONIAN MODEL

We consider a one-dimensional tight-binding chain (see Fig. 1), of $N$ spin $s = 5/2$ magnetic impurities coupled to ideal leads (sites $n < 1$ and $n > N$). We separate the electronic and impurity-spin degrees of freedom and treat the latter classically (static scatterers). The two-component electron wave function, $\psi = (\psi_1, \psi_2)$ is then governed by the Schrödinger equation with a Hamiltonian

$$ H = \begin{pmatrix} H_0 & 0 \\ 0 & H_0 \end{pmatrix} + \begin{pmatrix} H_{11} & H_{12} \\ H_{21} & H_{22} \end{pmatrix}. $$

FIG. 1. One-dimensional tight-binding chain with $N$ magnetic $s = 5/2$ impurities (mutually uncorrelated, each spin equally distributed among the six spin states) coupled to ideal impurity-free leads (sites $n < 1$ and $n > N$).
Here \( \mathbf{H}_0 \) is spin independent, with elements\(^{12} \)

\[
\{ \mathbf{H}_0 \}_{nm} = 2 \gamma \delta_{nn} - \gamma \delta_{nm} + \gamma \delta_{nm+1} + \mathcal{V}_n \delta_{nn},
\]

(2)

where \( \mathcal{V}_n \) is the potential at site \( n \) and \( \gamma = \hbar^2 / 2ma^2 \), with \( a \) being the "lattice constant." In the leads \( \mathbf{H}_0 \) itself gives rise to the usual dispersion relation \( \varepsilon(k) = 2 \gamma (1 - \cos ka) \).

In the following, \( \sigma = \uparrow = 1/2 \) and \( \sigma = \downarrow = -1/2 \). We restrict ourselves to zero magnetic field so that the block matrices \( \mathbf{H}_{\sigma \sigma} \) have elements given by

\[
\{ \mathbf{H}_{\sigma \sigma} \}_{nm} = \delta_{nm} J \gamma \sigma S_{n,z},
\]

(3)

which is a Heisenberg-like interaction of the spin of the electron (\( \sigma \)) with the \( z \)-component spin of the impurity \( S = (S_x, S_y, S_z) \). The off-diagonal block matrix \( \mathbf{H}_{\uparrow \downarrow} = \mathbf{H}_{\downarrow \uparrow} \) contains the interaction of the electron spin with the \( x \) and \( y \) components of the impurity spins which leads to spin-flip:

\[
\{ \mathbf{H}_{\downarrow \uparrow} \}_{nm} = \delta_{nn} J \gamma S_{n,x} - i J \gamma S_{n,y} / 2.
\]

(4)

We consider a sufficiently weak coupling between the impurity spins so that they can be considered mutually uncorrelated, i.e., no magnetic ordering. The \( z \)-component of each spin is equally distributed among the six spin states and the \( x \) and \( y \) components are uniformly distributed with the constraint that \( S^2 = S_x^2 + S_y^2 + S_z^2 = s(s + 1) \); see Fig. 1.

### III. TRANSPORT PROPERTIES

We study transport in the low-temperature linear response limit within the Landauer formalism:\(^{11} \)

\[
g = \frac{e^2}{\hbar} \sum \mathbf{T}_{\sigma \sigma'}(\varepsilon_F).
\]

(5)

Here \( \mathbf{T} \) is a \( 2 \times 2 \) matrix with the elements \( \mathbf{T}_{\sigma \sigma'} \) being the transmission probability of an electron from a state with spin \( \sigma' \) in one lead to a state with spin \( \sigma \) in the other lead. From Eq. (5) we now define the degree of spin polarization

\[
\zeta = \frac{I_1 \downarrow - I_1 \uparrow}{I_1 \downarrow + I_1 \uparrow} = \frac{T_{\downarrow \uparrow} + T_{\uparrow \downarrow} - T_{\downarrow \downarrow} - T_{\uparrow \uparrow}}{T_{\downarrow \uparrow} + T_{\uparrow \downarrow} + T_{\downarrow \downarrow} + T_{\uparrow \uparrow}},
\]

(6)

which we will focus on in this paper.

**Green function method.** The transmission matrix \( \mathbf{T} \) is related to the retarded Green function

\[
\mathbf{G}(\varepsilon) = [\varepsilon \cdot 1 - \mathbf{\tilde{H}} - \mathbf{\Sigma}(\varepsilon)]^{-1}
\]

via the Fisher-Lee relation\(^{14} \)

\[
\mathbf{T}_{\sigma \sigma'}(\varepsilon) = [\hbar v(\varepsilon)]^2 |[\mathbf{G}_{\sigma \sigma'}(\varepsilon)]_{N1}|^2,
\]

(8)

where \( v = \hbar^{-1} \partial \varepsilon / \partial k \) is the group velocity in the leads. In Eq. (7) the \( 2N \times 2N \) matrix \( \mathbf{\tilde{H}} \) is the Hamiltonian truncated to the \( N \) lattice sites with magnetic impurities. The effect of coupling to the leads is contained in the \( 2N \times 2N \) retarded self-energy matrix with elements\(^{12} \)

\[
\{ \mathbf{\Sigma}_{\sigma \sigma'}(\varepsilon) \}_{nm} = -\gamma e^{ikm\alpha} \delta_{\sigma \sigma'} \delta_{nm} (\delta_{ln} + \delta_{ln}).
\]

(9)

\( N=1 \) case. A chain with a single impurity is a simple illustrative example where analytical progress is possible. After performing the straightforward matrix inversion in Eq. (7) we find

\[
\zeta(\varepsilon) = -\frac{V J S_z}{V_1^2 + \varepsilon(4 \gamma - 2) + (JS)^2}.
\]

(10)

where \( J = (J_x, J_y, J_z)^T \). In zero magnetic field \( \langle S_z \rangle = 0 \) and \( \langle S_z^2 \rangle = 35/12 \). This implies that \( \zeta = 0 \) both with and without spin-flip, whereas the fluctuations are finite. The analytical averaging is of course complicated by the presence of \( S_z \) in the denominator, but for isotropic coupling \( J_x = J_y = J_z = 1 \), we have \( (JS)^2 = J_0^2 s(s + 1) \) so that \( S_z \) only shows up in the numerator, i.e.,

\[
\langle (\delta \zeta)^2 \rangle = \frac{35}{12} \frac{V_1^2 J_0^2}{[V_1^2 + \varepsilon(4 \gamma - 2) + J_0^2 s(s + 1)]^2}.
\]

(11)

In the absence of spin-flip \( (J_x = J_y = 0) \) the fluctuations are enhanced due to the replacement of \( s(s + 1) \rightarrow S_z^2 s(s + 1) \) in the denominator (the final expression for the fluctuations is much more complicated) and this means that spin-flip will lower the fluctuations of \( \zeta \). Of course this trend is strictly valid for \( N=1 \), but in a limited parameter range this trend is still true for larger \( N \) values.

**Finite \( N \) case.** For a finite number of impurities the problem is not analytically tractable and we study the problem numerically by generating a large ensemble (typically \( 10^5 \) members) of spin configurations. For each spin configuration we calculate Eqs. (7) and (8) numerically. In our simulations we use the following parameters: \( \varepsilon_x = \gamma \). \( J_z = \gamma / 2 \), \( V_n = 0 \) (i.e., we neglect spatial disorder), and varying spin-flip coupling strengths \( 0 \leq J_x = J_y \leq \gamma \).
This creasing and so do all average transmission probabilities limit in which \( P(z) \) scattering the distribution approaches that of the uniform distribution so that fluctuations can be comparable to \( |J_{\sigma}|/\hbar \).

IV. RESULTS AND DISCUSSIONS

Figure 2 shows the distributions \( P(\zeta), P(T_{\sigma\sigma}), \) and \( P(T_{\sigma\sigma'}) \) for \( N=10 \) and increasing strengths of the spin-flip coupling \( J_z = J_\gamma \). The distribution \( P(\zeta) \) is symmetric around \( \zeta = 0 \), which implies that on average there is no spin filtering, \( \langle \zeta \rangle = 0 \). The distribution \( P(\zeta) \) first gets narrower for spin-flip in the \([0.0.15\gamma]\) range (not shown) and then broadens as spin-flip further increases. For sufficiently strong spin-flip scattering the distribution approaches that of the uniform limit in which \( P(\zeta) = 1/2 \). In this limit \( P(T_{\sigma\sigma}) \) and \( P(T_{\sigma\sigma'}) \) coincide, and so do all average transmission probabilities \( \langle T_{\sigma\sigma} \rangle \). As we discuss below, the initial narrowing and subsequent broadening of \( P(\zeta) \) with spin flip gives rise to a minimum in the fluctuation of \( \zeta \) (Fig. 3).

Universal spin-polarization fluctuations. In the limit of a short spin-flip length \( \sqrt{\epsilon L} \) we in general find a uniform distribution \( P(\zeta) = 1/2 \) (Fig. 2). This uniform distribution yields the universal value \( \langle (\delta\zeta)^2 \rangle = 1/3 \) for the spin-polarization fluctuations. Figure 3 clearly shows that this universal value is attained for increasing spin-flip strengths and is indeed independent of \( N \). Interestingly, Fig. 3 also shows a minimum at around \( J_z = J_\gamma = 0.15 \gamma \). This minimum can be attributed to two competing energy scales: the longitudinal \( \sim J_z \) and the transverse \( \sim J_x, J_y \) parts of the \( s-d \) exchange interaction [Eqs. (3) and (4), respectively]. A simple “back-of-the-envelope” calculation shows that these two competing scales are equal for \( J_z = J_\gamma = \sqrt{2/3}(s+1)/3\gamma \) = 0.208\gamma. The vertical dashed line in Fig. 3 indicates this value. Observe that \( \langle (\delta\zeta)^2 \rangle \) becomes larger for increasing \( N \). This happens because \( P(\zeta) \) broadens for larger \( N \)’s (the traversing electrons see a wider region with random spins). This is similar to the broadening due to increasing spin flip strength.

We should mention that the distribution \( P(\zeta) \), and consequently \( \langle (\delta\zeta)^2 \rangle \), change dramatically for \( \epsilon_x < J_z \). In this regime, \( P(\zeta) \) becomes \( U \) shaped (not shown) because of the dominant filtering due to the “end states” with \( S_j = \pm 5/2 \). This qualitatively different \( P(\zeta) \) yields a monotonically decreasing \( \langle (\delta\zeta)^2 \rangle \) as a function of spin-flip strength. Here the universal \( \langle (\delta\zeta)^2 \rangle = 1/3 \) value is approached from above for large spin-flip strengths \( J_z = J_\gamma \sim \gamma \).

Suppression of conductance fluctuations. Whereas the fluctuations in the spin polarization \( \zeta \) remain finite in the strong spin-flip scattering regime (Fig. 3), we find that the fluctuations of the conductance \( g \) are strongly suppressed in this limit. This is illustrated in Fig. 4 which shows the average conductance and its fluctuations as a function of spin-flip scattering for \( N=10, 20, \) and \( 30 \). Note that \( \langle (\delta g)^2 \rangle^{1/2} \) is much more sensitive to spin-flip than \( g \). In addition, for all \( N \) we essentially have \( \langle (\delta g)^2 \rangle^{1/2} \sim \langle g \rangle \) for \( J_z = J_\gamma \rightarrow 0 \) and \( \langle (\delta g)^2 \rangle^{1/2} \sim \langle g \rangle \) for \( J_z = J_\gamma \rightarrow \gamma \). Figure 4 clearly shows the conductance fluctuations get suppressed for increasing \( N \). The horizontal dashed line shows the UCF value (0.73/2 = 0.365, see, e.g., Ref. 15) for a one-dimensional wire in the metallic regime. The spin-related conductance fluctuations do not approach a finite value for increasing spin-flip scattering. It actually seems to go to zero. This is in contrast to the spin-polarization fluctuations (Fig. 3), which attain a universal value \( \langle (\delta\zeta)^2 \rangle^{1/2} = 1/\sqrt{3} \) for strong spin-flip scattering. Incidentally, we observe that \( \langle (\delta g)^2 \rangle^{1/2} \) and \( \langle (\delta\zeta)^2 \rangle^{1/2} \) also present contrasting behavior for increasing \( N \) (and \( \epsilon_x > J_z \)): the former is suppressed while the latter is enhanced (cf. Figs. 3 and 4).

Spin disorder as spatial disorder. To some extent, the \( s-d \) site interaction considered here plays the role of spatial disorder in the system with a mean free path \( L \). Let us consider first the case with no spin-flip (i.e., \( J_z = J_\gamma = 0 \)). In this case, the term \( J_\sigma S_{\sigma \pm} \) acts as a “random” spin-dependent potential along the chain (here the site potential has some internal structure). As shown in Fig. 4 the conductance fluctuations for zero spin-flip scattering are larger than, slightly above, and slightly below, the UCF value for \( N=10, 20, \) and \( 30, \) respectively. For increasing \( N \) we go from the metallic regime (\( L = N a \ll 1/\epsilon_L \)) with vanishing fluctuations and a Gaussian \( P(g) \) strongly peaked near \( g \sim 2e^2/\hbar \) to the strongly localized regime (\( L \gg 1/\epsilon_L \)) where it is well known that \( P(g) \) is strongly peaked near \( g = 0 \) with a log-normal distribution so that fluctuations can be comparable to the
mean value. This is in accordance with numerical studies with different continuous distributions of the “on-site” potential (e.g., Gaussian or uniform distributions). In Fig. 4 the “small” mean values ⟨g⟩, for N = 10, 20, and 30, indicate the onset of localization with fluctuations comparable to the mean value. As N becomes larger conductance fluctuations are as expected suppressed.

Role of spin-flip scattering. Spin-flip clearly suppresses conductance fluctuations (Fig. 4). This can be understood from Eq. (4) being a complex number with a random phase which makes spin-flip act as a source of “decoherence” (the total wave function is, of course, fully coherent). Furthermore, spin-flip mixes all the \( S_{n_z} \) components on each site thus smoothing the potential seen by the traversing electron and hence reducing conductance fluctuations. This is true for both \( s_F > J_z \) [except for the window (0,0.15) in which \( P(\xi) \) narrows] and \( s_F < J_z \).

“Truly” universal fluctuations. Why is \( \langle \delta \xi \rangle^2 \) universal even for short spin-flip lengths \( \xi < L \) (strong spin-flip scattering) while \( \langle \delta g \rangle^2 \) is clearly suppressed below the usual UCF value in this limit? It is well known that conductance fluctuations are suppressed in the incoherent limit. More specifically, in one-dimensional wires with \( \xi < L \), \( \xi \) is some “dephasing length,” the suppression factor is \( \sqrt{L/\xi} \) (see Ref. 12). Interestingly, we can likewise understand the suppression of \( \langle \delta g \rangle^2 \) seen in our simulations by viewing spin-flip scattering as producing “dephasing” with \( \xi \sim 1/J_{1/3} \). For the spin-polarization fluctuations, however, the picture is slightly different: here we divide our system into \( N_L = L/\xi \) segments. To each of these we can associate an average spin polarization \( \langle \xi \rangle = 0 \) and a corresponding spin-polarization fluctuation \( \langle \delta \xi \rangle^2 \). Neither \( \langle \xi \rangle \) nor \( \langle \delta \xi \rangle^2 \) are additive quantities like \( g \) and \( \langle \delta g \rangle^2 \) (‘‘extensive versus intensive” properties). Sensible global averages for the whole system are then \( \bar{\xi} = \langle 1/N_L \rangle \sum_i \langle \xi_i \rangle = 0 \) and \( \langle \delta \xi \rangle^2 = \langle 1/N_L \rangle \sum_i \langle \delta \xi_i \rangle^2 \). We should expect \( \langle \delta \xi \rangle^2 = \langle \delta \xi_i \rangle^2 \) if the system is ergodic. Hence universal spin-polarization fluctuations are not suppressed for large spin-flip scattering in contrast to conductance fluctuations.

IV. CONCLUDING REMARKS

Spin-flip scattering in Mn-based wires reduces conductance fluctuations while enhancing spin-polarization fluctuations in a limited parameter range. Remarkably, spin-polarization fluctuations reach a universal value 1/3 for large spin-flip scattering in which the conductance fluctuations vanish. This universal value should manifest itself in time- and polarization-resolved photoluminescence measurements. More important, these sizable spin fluctuations may limit the possibilities for steady spin injection in these systems.

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